

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	
S1	124652	Semiconductor adj device	US-PGPUB; USPAT	OR	OFF	2006/0
S2	73913	S1 and etch\$4	US-PGPUB; USPAT	OR	OFF	2005/12/23
S3	3362	S2 and high adj aspect adj ratio	US-PGPUB; USPAT	OR	OFF	2005/12/23 15:00
S4	620	S3 and (RF or radio adj frequency) adj power	US-PGPUB; USPAT	OR	OFF	2005/12/23 15:01
S5	6	S4 and (first or second) adj frequency	US-PGPUB; USPAT	OR	OFF	2005/12/23 15:01
S6	45	S4 and etch\$4 adj dielectric adj layer	US-PGPUB; USPAT	OR	OFF	2005/12/27 08:46
S7	3	S6 and etch adj gas	US-PGPUB; USPAT	OR	OFF	2005/12/23 15:26
S8	1	("6743727").PN.	USPAT; USOCR	OR	OFF	2005/12/23 16:26
S9	0	("2004/0221958").URPN.	USPAT	OR	OFF	2005/12/27 08:46
S10	124785	Semiconductor adj device	US-PGPUB; USPAT	OR	OFF	2005/12/27 08:48
S11	73993	S10 and etch\$4	US-PGPUB; USPAT	OR	OFF	2005/12/27 08:48
S12	3367	S11 and high adj aspect adj ratio	US-PGPUB; USPAT	OR	OFF	2005/12/27 08:48
S13	620	S12 and (RF or radio adj frequency) adj power	US-PGPUB; USPAT	OR	OFF	2005/12/27 08:48
S14	0	S13 and etch\$4 adj dielectric adj layer	EPO; JPO; DERWENT	OR	OFF	2005/12/27 08:48
S15	1	("6500314").PN.	USPAT; USOCR	OR	OFF	2005/12/27 10:01
S16	1	("6436253").PN.	USPAT; USOCR	OR	OFF	2005/12/27 10:16
S17	1	("4464223").PN.	USPAT; USOCR	OR	OFF	2005/12/27 10:16
S18	8	((("5626716") or ("5656123") or ("5716485") or ("6127278") or ("6303510") or ("6387287") or ("6433297") or ("6506674"))).PN.	USPAT; USOCR	OR	OFF	2005/12/27 10:36
S19	124785	Semiconductor adj device	US-PGPUB; USPAT	OR	OFF	2005/12/28 08:54
S20	73993	S19 and etch\$4	US-PGPUB; USPAT	OR	OFF	2005/12/28 08:54

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S21	3367	S20 and high adj aspect adj ratio	US-PGPUB; USPAT	OR	OFF	2005/12/28 08:54
S22	620	S21 and (RF or radio adj frequency) adj power	US-PGPUB; USPAT	OR	OFF	2005/12/28 08:54
S23	6	S22 and (first or second) adj frequency	US-PGPUB; USPAT	OR	OFF	2005/12/28 08:54
S24	45	S22 and etch\$4 adj dielectric adj layer	US-PGPUB; USPAT	OR	OFF	2005/12/28 08:54
S25	3	S24 and etch adj gas	US-PGPUB; USPAT	OR	OFF	2005/12/28 08:54
S26	1	("6743727").PN.	USPAT; USOCR	OR	OFF	2005/12/28 08:54
S27	0	("2004/0221958").URPN.	USPAT	OR	OFF	2005/12/28 08:54
S28	124785	Semiconductor adj device	US-PGPUB; USPAT	OR	OFF	2005/12/28 08:54
S29	73993	S28 and etch\$4	US-PGPUB; USPAT	OR	OFF	2005/12/28 08:54
S30	3367	S29 and high adj aspect adj ratio	US-PGPUB; USPAT	OR	OFF	2005/12/28 08:54
S31	620	S30 and (RF or radio adj frequency) adj power	US-PGPUB; USPAT	OR	OFF	2005/12/28 08:54
S32	0	S31 and etch\$4 adj dielectric adj layer	EPO; JPO; DERWENT	OR	OFF	2005/12/28 08:54
S33	1	("6500314").PN.	USPAT; USOCR	OR	OFF	2005/12/28 08:54
S34	1	("6436253").PN.	USPAT; USOCR	OR	OFF	2005/12/28 08:54
S35	1	("4464223").PN.	USPAT; USOCR	OR	OFF	2005/12/28 08:54
S36	8	((("5626716") or ("5656123") or ("5716485") or ("6127278") or ("6303510") or ("6387287") or ("6433297") or ("6506674"))).PN.	USPAT; USOCR	OR	OFF	2005/12/28 08:54
S37	1	("6942816").PN.	USPAT; USOCR	OR	OFF	2005/12/28 08:59
S38	4	((("6824627") or ("6942816") or ("6872281") or ("6391787"))).PN.	USPAT; USOCR	OR	OFF	2005/12/28 09:14
S39	2622	156/345;216/54,63,67,71;438/712.734.ccls.	US-PGPUB; USPAT	OR	OFF	2006/02/03 16:11
S40	3	S24 and S39	US-PGPUB; USPAT	OR	OFF	2005/12/28 09:17
S41	5138	156/345;216/54,63,67,71;438/712.734;257/187,213;427/569,579,534.ccls.	US-PGPUB; USPAT	OR	OFF	2006/02/03 16:23

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S42	126691	Semiconductor adj device	US-PGPUB; USPAT	OR	OFF	2006/02/03 16:23
S43	75167	S42 and etch\$4	US-PGPUB; USPAT	OR	OFF	2006/02/03 16:23
S44	3414	S43 and high adj aspect adj ratio	US-PGPUB; USPAT	OR	OFF	2006/02/03 16:23
S45	623	S44 and (RF or radio adj frequency) adj power	US-PGPUB; USPAT	OR	OFF	2006/02/03 16:23
S46	45	S45 and etch\$4 adj dielectric adj layer	US-PGPUB; USPAT	OR	OFF	2006/02/03 16:23
S47	7	S41 and S46	US-PGPUB; USPAT	OR	OFF	2006/02/03 16:24
S48	0	(second adj etch step)and (first adj frequency adj fourth adj power) and (second adj frequency adj fifth power)	US-PGPUB; USPAT	OR	OFF	2006/05/12 15:18